



- (C) Tunnel diode (D) Gunn diode

- f. In parametric amplifiers used in microwave communication systems, the amplification is limited by
- (A) type of biasing (B) a maximum of 10  
(C) pump energy (D) frequency of operation
- g. A microwave junction is supposed to be matched at all ports, if in the S matrix,
- (A) all the diagonal elements are zero.  
(B) all the diagonal elements are equal but not zero.  
(C) all the diagonal elements are complex.  
(D) is hermitian.
- h. The positions of the probe for half power points in the slotted line of a microwave bench are interpreted to measure
- (A) guide wavelength (B) load impedance  
(C) source frequency (D) high SWR
- i. The main disadvantage of the two-hole directional coupler is
- (A) Poor coupling factor (B) poor directivity  
(C) high SWR (D) narrow bandwidth
- j. A PIN diode is frequently used as a
- (A) harmonic generator (B) peak clipper  
(C) voltage regulator (D) switching diode for frequencies upto GHz range.

**Answer any FIVE Questions out of EIGHT Questions.**  
**Each question carries 16 marks.**

- Q.2** a. Define the characteristic impedance of a transmission line. Derive the transmission line equation. (8)
- b. A lossless transmission line has a normalised load admittance  $(Y_R / G_0) = 2.75 + j1.75$ . The observed standing wave ratio on the line is 4.0. It is proposed to use a short circuited stub to match the load to the line.
- (i) Determine the electrical distance from the load to the place where the stub

should be located.

- (ii) Find the length of the stub in terms of wave length. (8)

- Q.3** a. Define the following terms related to directional coupler. Also write S matrix for the same. (i)  
 Directivity (ii) Coupling factor (iii) Insertionloss (iv)  
 Isolation. (6)

- b. Mention some of the important features of a slot line and a co-planar line. (6)

- c. In a TWT, anode voltage  $V_a = 1600$  volts, beam current  $I_o = 20$  mA, characteristic impedance  $Z_o = 300 \Omega$ , length =  $4\lambda$ , and losses of 3 dB. Find the gain and output. (4)

- Q.4** a. Explain the operation of a faraday rotation isolator with the help of neat sketch. List the application of ferrite isolator. (8)

- b. A microstrip line of width  $w = 2$  mms is mounted on a quartz substrata of height  $h = 0.4$  mm. The dielectric constant of quartz is 3.8 and the loss tangent is 0.0001. Find the effective permittivity and characteristic impedance of the line at 9GHz. (8)

- Q.5** a. List the basic characteristics of a circulator. Discuss any one type with uses. (6)

- b. Derive the formula for the attenuation constant of a wave guide in terms of the total power flow along the wave guide and the losses per unit length of the waveguide. (6)

- c. Enumerate the advantages and disadvantages of MICs. (4)

- Q.6** a. How would you measure microwave noise bandwidth and noise factor? (6)

- b. Determine the transmitter power required in a microwave communication system with the following specifications.

Carrier frequency : 4 GHz.

Minimum power at receiver input : -65 dBw.

Gain of transmitting and receiving antennas : 45 dB

Distance between antennas : 60 Km.

If the distance between the antenna is doubled, what happens to the power loss. (6)

- c. Mention the advantages and disadvantages of microwave communication. (4)

- Q.7** a. Explain the principle and operation of two-cavity klystron with a neat sketch. (8)

- b. How does the function of the magnetic field in a TWT differ from its function in a

magnetron?

(4)

- c. A Gunn diode is working in transit time modes at 12 GHz. The domain of charges move at  $10^7$  cm/sec speed. Calculate the length of the device. Can the device work at 14 GHz? If Yes, what will be the mode of operation? (4)

**Q.8**

- a. Explain the principles of operation of TRAPATT diode with the help of voltage and current waveforms. (8)

- b. Two cavity klystron has the following parameters. Beam voltage  $V_0 = 20$  KV, operating frequency  $f = 10$  GHz, Beam current  $Z_0 = 10$  GHz, Beam comling coefficient  $\beta: \beta_0 = 1$ , dc electron beam current density =  $10^{-8}$  c/m<sup>3</sup>, signal voltage  $V_i = 10$  V (rms) shunt resistance of cavity  $R_{sh} = 15$  k $\Omega$ , total shunt resistance including load  $R = 35$  k $\Omega$ . Find (i) Plasma frequency (ii) the induced current at the output cavity (iii) Power gain (iv) electronic efficiency. (8)

**Q.9**

Write short notes on any **TWO** of the following:

(i) Measurement of microwave power.

(ii) Reflex Klystron.

(iii) Duct Propagation.

(iv)

Line of sight communications.

(2 x

8)